NSN 5961-01-151-5208

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Inclosure Material: Metal Overall Length: Between 0.240 inches and 0.260 inches Terminal Length: Between 1.500 inches and 1.750 inches Overall Diameter: Between 0.335 inches and 0.370 inches Internal Configuration: Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Hermetically sealed case

Criticality Code Justification:

Feat

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

140.0 collector to base voltage/static/emitter open

Current Rating Per Characteristic:

1.00 amperes source cutoff current

Power Rating Per Characteristic:

800.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

Radiation hardness controlled item; junction pattern arrangement: npn

Nuclear Hardness Critical Feature:

Hardened

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

3 uninsulated wire lead

Specification Data:

81349-mil-s-19500/391a w amend 3 government specification

Shelf Life:

N/a

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Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0

